Nuclear spin decoherence of neutral ³¹P donors in silicon: Effect of environmental ²⁹Si nuclei

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Spectral diffusion arising from ²⁹Si nuclear spin flip-flops, known to be a primary source of electron spin decoherence in silicon, is also predicted to limit the coherence times of neutral donor nuclear spins in silicon. Here, the impact of this mechanism on ³¹P nuclear spin coherence is measured as a function of ²⁹Si concentration using *X*-band pulsed electron nuclear double resonance. The ³¹P nuclear spin echo decays show that decoherence is controlled by ²⁹Si flip-flops resulting in both fast (exponential) and slow (nonexponential) spectral diffusion processes. The decay times span a range from 100 ms in crystals containing 50% ²⁹Si to 3 s in crystals containing 1% ²⁹Si. These nuclear spin echo decay times for *neutral* donors are orders of magnitude longer than those reported for *ionized* donors in natural silicon. The electron spin of the neutral donors "protects" the donor nuclear spins by suppressing ²⁹Si flip-flops within a "frozen core," as a result of the detuning of the ²⁹Si spins caused by their hyperfine coupling to the electron spin.

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Donors in silicon have been considered for use in quantum information since the early days of the field [1,2]. Donors have both electron and nuclear spins which can be manipulated independently, and both have been considered for use as potential quantum bits (qubits). While donor electron spins have received a majority of the attention [3–6], the nuclear spins are capable of much longer coherence times [7–9]. This characteristic was utilized in the original Kane proposal for quantum computing [1] and gained attention later for building a quantum memory [7]. While exceptionally long T_2 times of donor nuclear spins in silicon have already been demonstrated [7,8], the mechanics of nuclear spin decoherence are not yet fully understood. In this study, we focus on neutral ³¹P donor nuclear spins in the silicon host environment.

Spectral diffusion due to spin- $\frac{1}{2}$ ²⁹Si nuclei is a major source of decoherence for donor electron spins in silicon [10–13] and has been predicted to be a major source of decoherence for donor nuclear spins as well [10]. While the predicted coherence time for neutral ³¹P donor nuclear spins in natural silicon (containing 4.7% ²⁹Si) was 0.5 s, several experimental works reported much shorter times (from hundreds of microseconds to tens of milliseconds) [14–17]. Coherence times presented here and by Wolfowicz *et al.* [18] show that the limit from ²⁹Si spectral diffusion is actually longer than inferred from those previous experiments. To resolve the role of ²⁹Si spectral diffusion, we measure neutral ³¹P nuclear spin coherence times in silicon crystals with ²⁹Si concentrations ranging from 1% to 50% [12].

We find an inverse linear dependence of ³¹P nuclear spin coherence time on ²⁹Si concentration (*f*), ranging from 100 ms at 50% ²⁹Si to 3 s at 1% ²⁹Si. The nuclear spin coherence time is about 1 s in natural silicon at 1.7 K, close to predictions of central spin stochastic models [10]. However, contrary to the predictions, the observed spin echo decays are nonexponential. The decay times are two orders of magnitude longer than those measured for ionized donors in natural silicon [16,17] or in NMR experiments on degenerately doped silicon [14,15].

Apparently, the electron bound to a neutral donor protects the nuclear spin coherence from ²⁹Si flip-flops by detuning nearby ²⁹Si nuclear spins (a "frozen core") [19–21]. This protection might not be required in high-purity isotopically enriched silicon, with a low content of ²⁹Si, where ²⁹Si-induced spectral diffusion is no longer a dominant source of decoherence [8,9,22].

Four phosphorus-doped silicon crystals with different concentrations of ²⁹Si isotopes were used in this work (Table I). In all crystals, the donor concentration was about 10^{15} /cm³ which is low enough to ensure that other decoherence effects arising from dipolar interactions with donor electron spins are small compared to the measured ²⁹Si spectral diffusion effects. The pulsed electron nuclear double resonance (ENDOR) experiments were conducted using a Bruker Elexsys E580 spectrometer. Nuclear spin coherence times were measured using an electron-mediated nuclear spin Hahn echo experiment [7]. The combination of microwave and rf pulses enable a superposition state to be created on the donor electron, transferred to the ³¹P nucleus, manipulated on the nucleus, and then transferred back to the electron for readout. For temperatures below 5 K, when the electron T_1 relaxation was longer than 10 s, a light-emitting diode (LED, 1050 nm) was flashed for 20 ms after each pulsed experiment in order to accelerate electron spin thermalization between repeated measurements. The "tidy" rf pulse to achieve nuclear spin thermalization was not required in these nuclear T_2 experiments [7,23]. Most of the data shown were measured with a static magnetic field (~ 0.35 T) oriented along a [001] crystal axis. Other field orientations were also examined to test the orientation dependence of the nuclear spin coherence times.

The Hahn echo decay for phosphorus donor nuclear spins in natural silicon (f = 4.7%) at 1.7 K is shown in Fig.1(a). This decay is nonexponential and can be best fit using [25,26]

$$v(\tau) = \exp\left[-\frac{2\tau}{T_2} - \left(\frac{2\tau}{T_{\text{SD}}}\right)^n\right],\tag{1}$$

TABLE I. Four ³¹P-doped silicon samples used in this work. In each sample, the ²⁹Si concentration was determined by secondary ion mass spectroscopy (SIMS), and donor concentration was determined from ESR spin counting and independently confirmed by instantaneous diffusion slope measurements [12]. All crystals were float-zone with the exception of ²⁹Si-5% (natural Si) which was Czochralski. All crystals had a volume on the order of a few cubic millimeters.

Sample	²⁸ Si (%)	²⁹ Si (%)	³⁰ Si (%)	³¹ P/cm ³
²⁹ Si-1%	98.1	1.2	0.7	0.67×10^{15}
²⁹ Si-5%	92.2	4.7	3.1	0.8×10^{15}
²⁹ Si-10%	87.2	10.3	2.5	2.9×10^{15}
²⁹ Si-50%	50.2	47.9	1.9	1.2×10^{15}

where τ is the time interval between $\pi/2$ and π pulses in a Hahn echo experiment. This functional form contains two decoherence terms. T_2 can be associated with various decoherence processes, including T_1 -related processes and a broad variety of spectral diffusion mechanisms in a *fast-motional* regime, while T_{SD} is associated with spectral diffusion processes in a *slow-motional* regime [10,27,28]. As we will discuss, fast and slow-motional regimes in our experiments are defined by how the rates of ²⁹Si nuclear spin flip-flops compare to the overall rate of decoherence. The stretch factor *n* is in the range between 2 and 3 [10,25,26,28].

The temperature dependence of the extracted nuclear spin T_2 and T_{SD} for phosphorous donors in natural silicon is shown in Fig. 1(b). The T_{SD} term could only be extracted below 5 K because the linear T_2 term dominated the decays at higher temperatures. As seen from Fig. 1(b), electron T_1 controls the nuclear T_2 at temperatures higher than 6 K. However, electron T_1 continues growing below that temperature, while both T_2 and T_{SD} saturate at around 1 s showing little temperature dependence down to 1.7 K. This weak temperature dependence is consistent with ²⁹Si-induced spectral diffusion being a dominant decoherence process for ³¹P nuclear spins below 5 K [10].

The dependence of T_2 and T_{SD} on ²⁹Si concentration provides further evidence that ²⁹Si flip-flops are a major source of decoherence in our samples. Nuclear spin echo decays for all four samples from Table I are shown in Fig. 2 (electron spin echo decay for ³¹P donors in natural silicon is also shown for comparison). The extracted T_2 and T_{SD} at 1.7 K are plotted against ²⁹Si concentration in Fig. 3(a) showing a relatively inverse linear dependence for both times. Within the experimental errors, the parameter *n*, shown in Fig. 3(b), stays constant at about 2.5 for all concentrations from 1% to 50%. T_2 and T_{SD} were also measured with the magnetic field oriented at different angles with respect to the crystal axis. However, no noticeable orientation dependence was observed within experimental errors (10%) in either T_2 or T_{SD} .

Three other decoherence mechanisms must be considered here as potential contributors to nuclear spin decoherence at low temperatures. These processes have been found to be significant in decohering electron spins of neutral donors. All three mechanisms are related to dipolar interactions with electron spins of other donors. The first two processes are cases of spectral diffusion arising (1) from T_1 -driven flips of

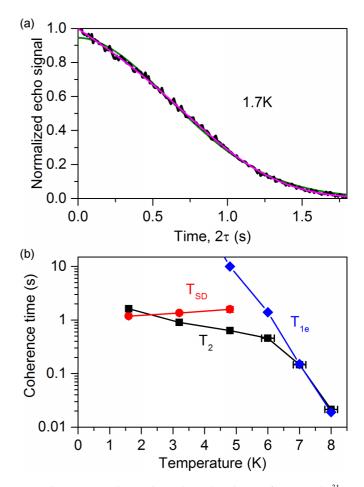


FIG. 1. (a) Nuclear spin Hahn echo decays for neutral ³¹P donors in natural silicon (f = 4.7%) at 1.7 K with magnetic field (~0.35 T) oriented along [001]. The pink curve is a fit of the data using Eq. (1). The green curve is a fit to $\exp[-(2\tau/T_{SD})^n]$ demonstrating that using only one exponential term does not provide a good fit. A detailed comparison of the two fits for all four samples used in this work is presented in the Supplemental Material [24]. (b) Temperature dependencies of ³¹P nuclear spin T_2 and T_{SD} (black squares and red circles, respectively) and electron spin T_{1e} times (blue diamonds) for neutral phosphorus donors in natural silicon. Vertical error bars in (b) are smaller than their symbols.

electron spins of nearby donors [4,28], and (2) from electron spin flip-flops in nearby donor pairs [4,29]. Both cases are much less effective in decohering nuclear spins than electron spins since their effect scales proportionally with nuclear and electron gyromagnetic ratios ($\sim \frac{1}{1600}$ in the case of ³¹P nuclei). Using the electron T_2 times reported in Ref. [4], assuming donor densities of 10^{15} /cm³ (as used here) and considering temperatures below 4.8 K, we can then estimate the nuclear T_2 and T_{SD} from spectral diffusion processes (1) and (2) to be longer than 200 s. Thus, processes (1) and (2) are too slow to explain our T_2 data in Fig. 3(a).

The third dipolar-related process to be considered is a "direct" flip-flop process [30]. This involves a spin flip-flop between an electron of a "central" donor and an electron of a neighboring donor [this is in contrast to "indirect" flip-flops described in (2) above]. Unlike other dipolar-related mechanisms, the effect of direct flip-flops does not scale with

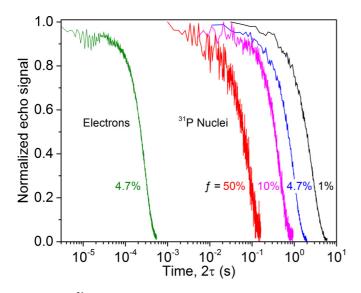


FIG. 2. ³¹P nuclear spin Hahn echo decays for phosphorus donors in silicon with different ²⁹Si concentrations, measured at 1.7 K and magnetic field along [001]. The ²⁹Si concentrations (f) are indicated for each curve. Electron spin Hahn echo decay for phosphorus donors in natural silicon is shown for comparison. See Supplemental Material [24] for the fits of these decays using Eq. (1).

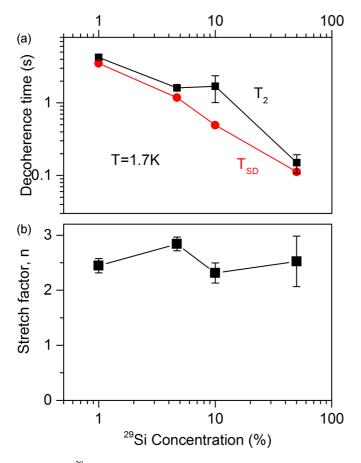


FIG. 3. ²⁹Si concentration dependence of (a) spectral diffusion times T_2 and T_{SD} , and (b) stretch factor *n* for ³¹P nuclear spins of phosphorus donors in silicon at 1.7 K. Some error bars in (a) are smaller than their symbols.

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gyromagnectic ratio, decohering nuclear spins as rapidly as electron spins. Direct flip-flops have been reported to limit electron spin coherence to 0.8 s for donors at 10^{14} /cm³ in isotopically purified ²⁸Si crystals (45 ppm of ²⁹Si) [4]. However, the inhomogeneous broadening in our samples (Table I) is 100–900 μ T which is 20–200 times broader than the 3 μ T found in the aforementioned 45 ppm crystals [4,12]. Taking into account the donor density in our samples we estimate that the direct flip-flop contribution to ³¹P nuclear decoherence is about 5 s in our ²⁹Si-1% sample and is even longer (> 10 s) in the other three samples.

The effect of ²⁹Si spectral diffusion on nuclear spin coherence of neutral ³¹P donors in silicon has been examined theoretically in the framework of a central spin problem while modeling ²⁹Si spin flip-flops as a classical stochastic process [10]. For natural silicon, a ³¹P nuclear spin coherence time of 0.5 s was predicted with the field oriented along [001]. This prediction is very close to what was measured at that orientation in this work. Simulations of nuclear spin coherence showed an approximately inverse dependence on f, which also correlates with our results. However, the theory predicted exponential T_2 decays with n = 1, while our experiment shows nonexponential decays. The predicted orientation dependence was also not observed in our experiment.

It is instructive to compare the decoherence of ³¹P donor electron and nuclear spins caused by ²⁹Si flip-flops. The electron and nuclear spin echo decays differ in two ways: (i) the nuclear spin echo decays are over three orders of magnitude longer than electron spin echo decays, and (ii) the nuclear spin echo decays contain both exponential and nonexponential components, unlike the electron spin echo decays that are dominated by the nonexponential term [12]. Both electrons and ³¹P nuclei see the same bath of ²⁹Si nuclear spins, with the bath's dynamics suppressed in the "frozen core" where the nuclear spins are detuned by the donor electron [19–21]. The main difference between electron and ³¹P nuclear spins is the strength of their interactions with the ²⁹Si spin bath. Contact hyperfine interactions for an electron spin are much stronger than dipolar interactions for a ³¹P nuclear spin, therefore, the same ²⁹Si bath decoheres the electron spin faster than the nuclear spin. This difference in the coherence time scale explains (i) and is also the key to understanding (ii).

²⁹Si flip-flops can cause fast- or slow-motional effects depending on whether the flip-flop rate is fast or slow compared to the strength of the pair's interaction with the central spin [10,25,28,31]. Equivalently, the fast and slow regimes can be discriminated by comparing the flip-flop period to the overall coherence time scale (2τ) of the central spin [28]. There is a broad distribution of ²⁹Si flip-flop rates, with the fastest rates being ~ 100 Hz and 10 Hz in nearest- and next-nearest-neighbor pairs, and much slower rates in more distant pairs. All these rates correspond to times much longer than 2τ (~ 600 μs) when measuring electron spin echoes. In this case, all flip-flops are in a slow-motional regime, causing slow spectral diffusion with nonexponential echo decays as seen in experiment [12] and understood theoretically [10,26,32]. For nuclear spins, on the other hand, the time scale of the experiments lies within the broad distribution of ²⁹Si flip-flop times. Thus, there are fast and slow flip-flopping pairs that contribute to the decoherence, and consistently both exponential and nonexponential components are present in the decays.

The ³¹P nuclear spin coherence time in natural silicon presented here is longer than measured earlier for ionized donors or donors in degenerately doped silicon. NMR measurements of ³¹P nuclear spin decoherence in degenerately doped silicon have found times about two orders of magnitude shorter [14,15]. Ionized donors measured with EDMR had a coherence time of 18 ms [16], and single donors measured with an SET had a coherence time of 60 ms [17]. These measurements of ionized donors are in agreement with cluster correlation expansion simulations by Witzel *et al.* (~ 30 ms) [32]. The longer coherence time for our isolated neutral ³¹P donors supports the "frozen core" picture [19–21] where most ²⁹Si pairs near a central spin are too detuned by the donor electron spin to flip-flop.

In conclusion, we have experimentally studied the effect of environmental ²⁹Si nuclear spins on neutral donor nuclear spin

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decoherence in silicon. Two contributors have been resolved arising from fast and slow flip-flopping ²⁹Si nuclear spin pairs. We find that both contributions exhibit a linear dependence on ²⁹Si concentration. Our results demonstrate long coherence times for neutral donor nuclear spins, ranging from 100 ms in crystals containing 50% ²⁹Si to 3 s in crystals containing 1% ²⁹Si, and are in agreement with the picture that an electron bound to a donor protects the donor nuclear spins from ²⁹Si flip-flops.

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